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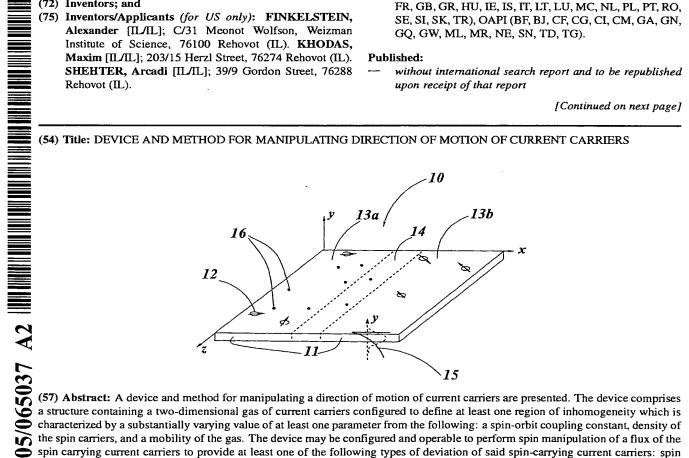
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- (71) Applicant (for all designated States except US): YEDA RESEARCH AND DEVELOPMENT COMPANY LTD. [IL/IL]; At The Weizmann Institute of Science, P.O.Box 95, 76100 Rehovot (IL).
- (72) Inventors; and
- (75) Inventors/Applicants (for US only): FINKELSTEIN,

- (74) Agent: REINHOLD COHN AND PARTNERS; P.O.B. 4060, 61040 Tel Aviv (IL).
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the spin carriers, and a mobility of the gas. The device may be configured and operable to perform spin manipulation of a flux of the spin carrying current carriers to provide at least one of the following types of deviation of said spin-carrying current carriers: spin dependent refraction, spin dependent reflection and spin dependent diffraction on desired deviation angles of a direction of motion of the spin-carrying current carriers being incident on said at least one region of inhomogeneity. The device may also be configured and operable to allow emission of the current carriers from a diffusive region at one side of the region of inhomogeneity to a ballistic region at the opposite side of the region of inhomogeneity to provide the current carriers propagation in multiple directions in the ballistic region with a wide angular range of these directions.



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